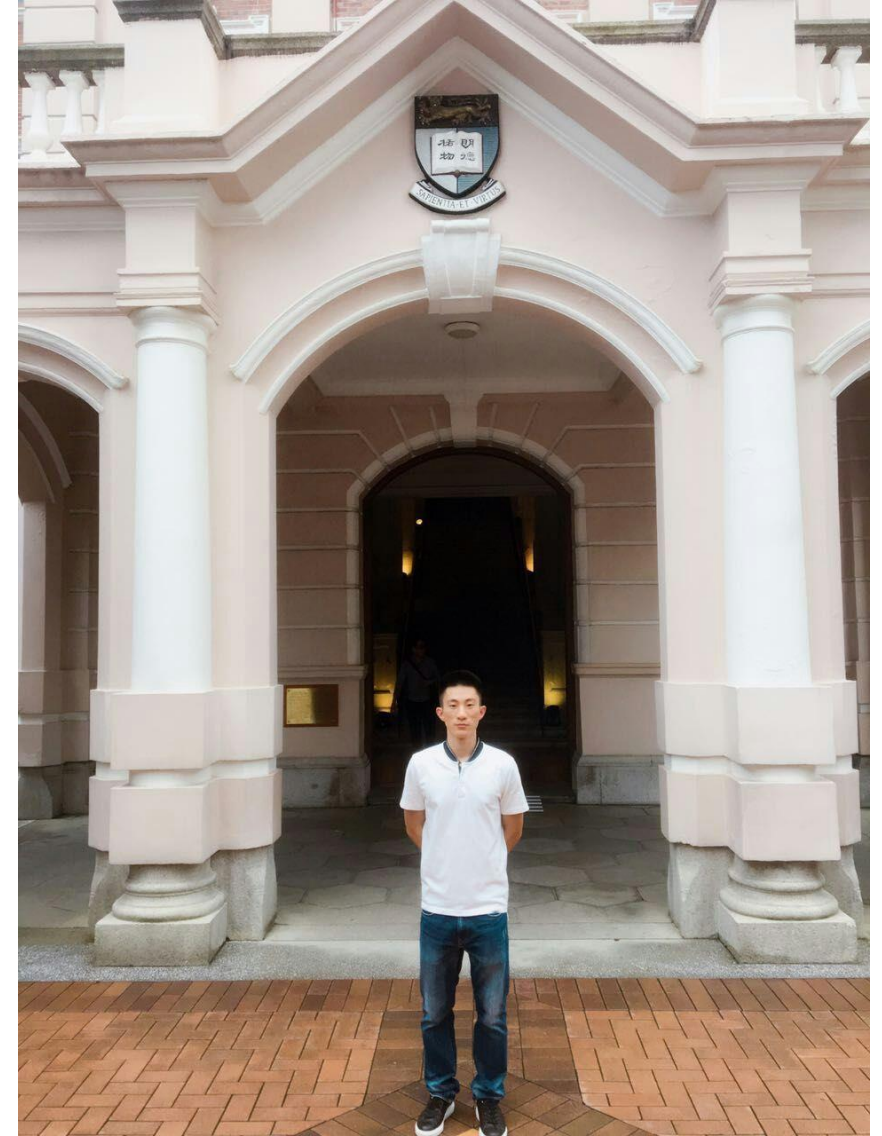


Hello! Everyone

I am the speaker of this paper,
titled “A Memristor-Based Spiking
Neural Network with
High Scalability and Learning
Efficiency”

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**A Memristor-Based Spiking Neural Network with
High Scalability and Learning Efficiency**



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1. Introduction

1.1 The fundamentals of SNNs

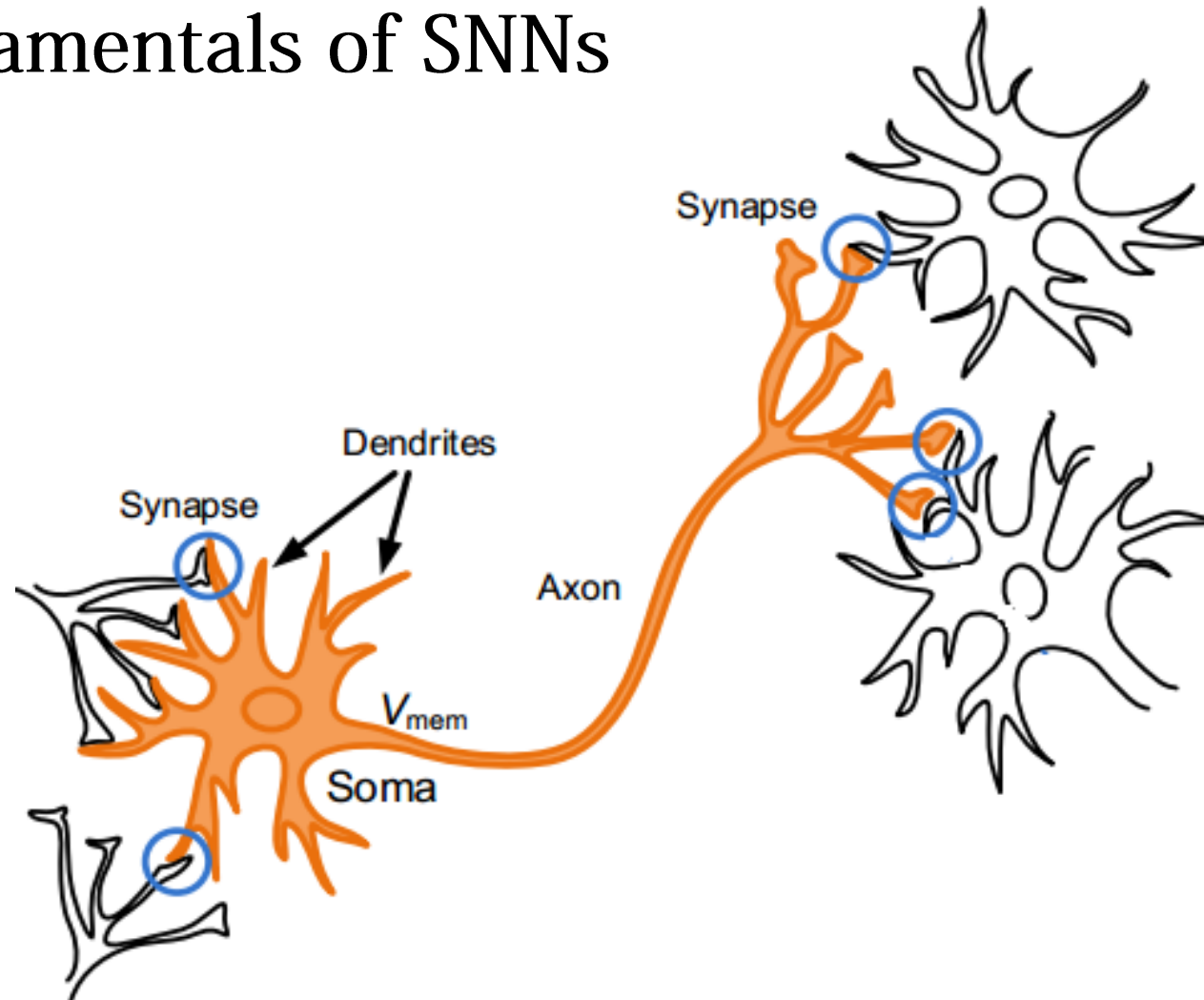


Fig 1. The schematic of biological neural system, mainly composed of spiking neuron, axon, dendrite, and synapse.

1. Introduction

1.1 The fundamentals of SNNs

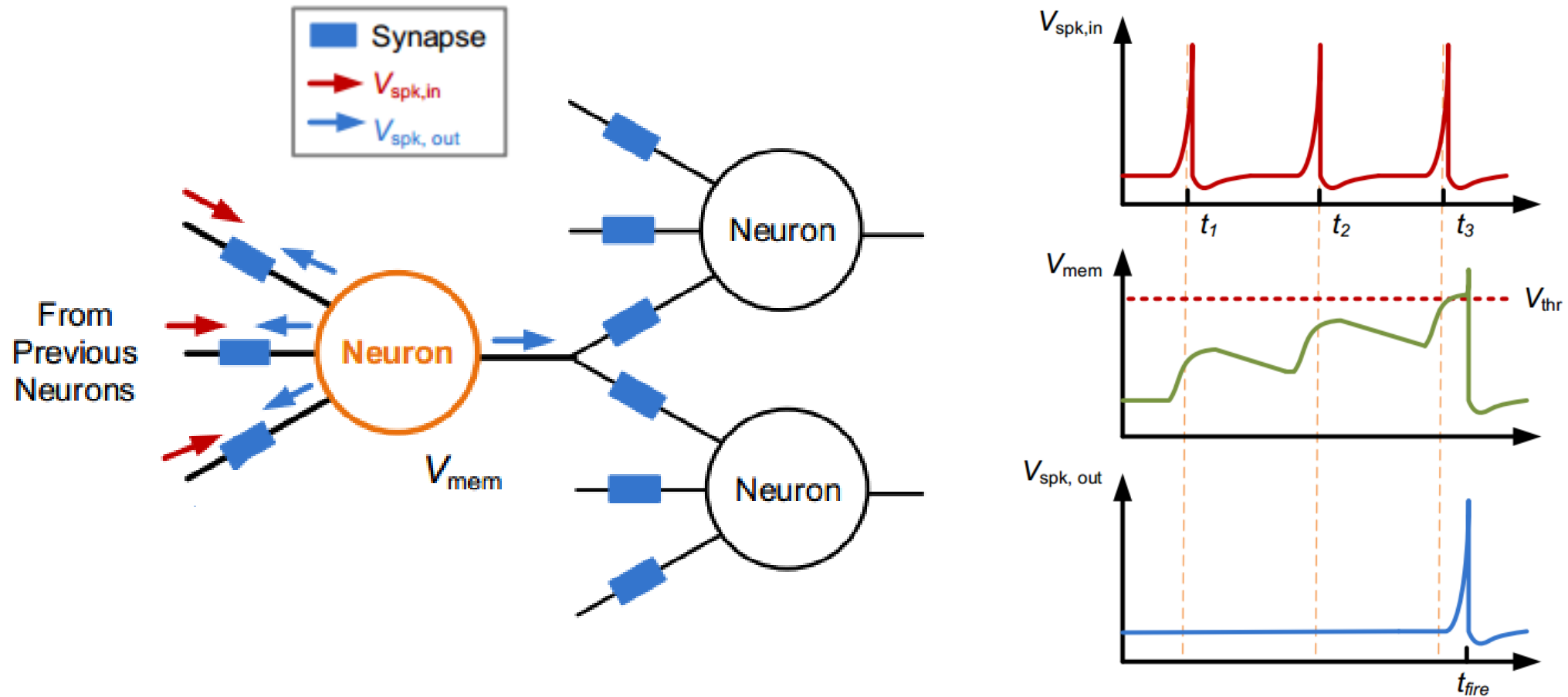
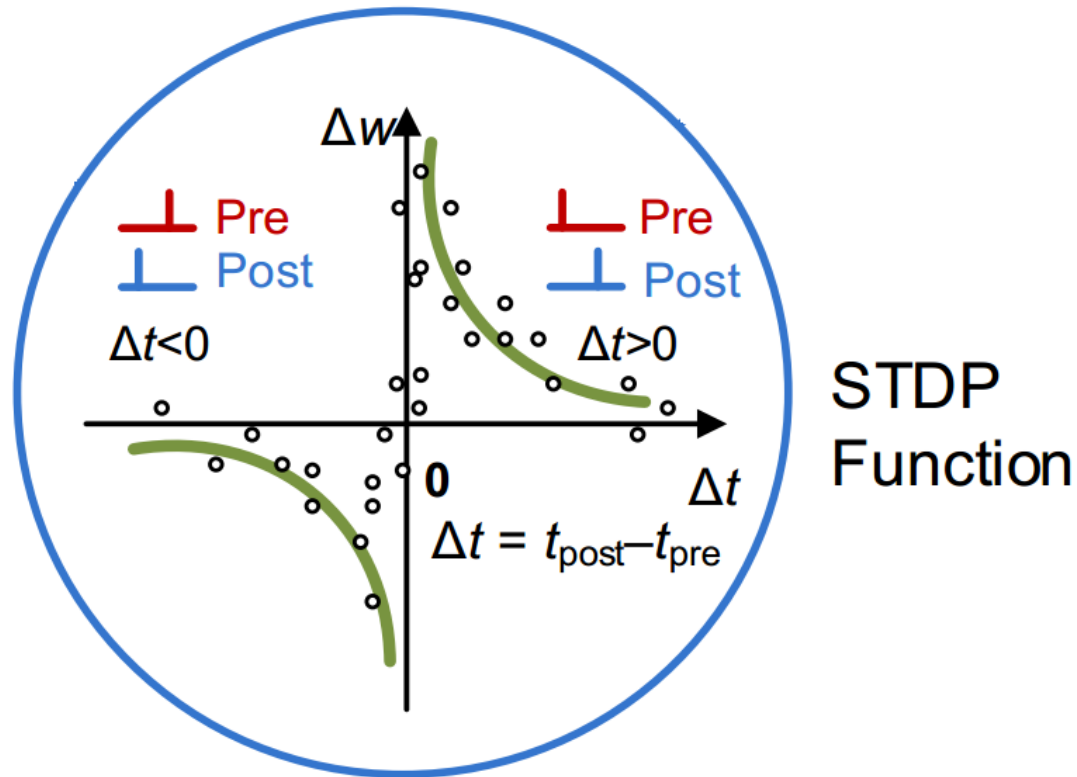


Fig 2. The spiking neural model abstracted from biological neural systems, and the working mechanism of a typical integrate and firing neuron.

1. Introduction

1.1 The fundamentals of SNNs



With STDP, repeated pre-synaptic spike arrival before post-synaptic spike leads in a larger synaptic weight; whereas repeated spike arrival after postsynaptic spikes leads to a smaller synaptic weight.

Fig. 3 Synaptic weight w can be modulated by the pre- and post-synaptic spikes, which is plotted as the STDP function.

1. Introduction

1.2 Two kinds of network architecture for STDP-based SNNs

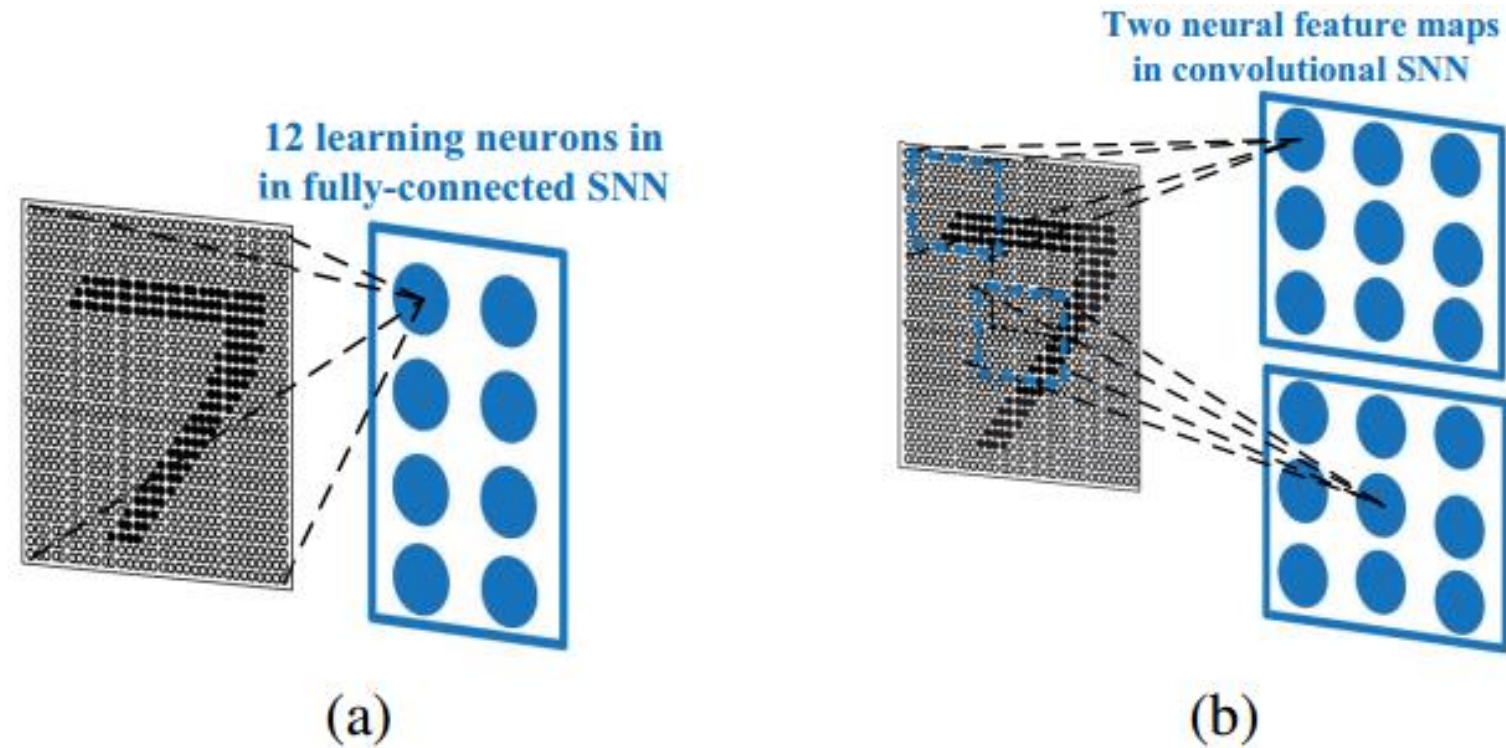


Fig. 4 The network architecture of one learning layer for fully-connected and convolutional architectures of SNN.

1. Introduction

1.3 Another two mechanisms demanded for STDP-based SNN

Lateral inhibition:

Lateral inhibition forces neurons (or different neural feature maps) in the same layer to learn different patterns by preventing other neurons from firing when one neuron has already responded to the input pattern .

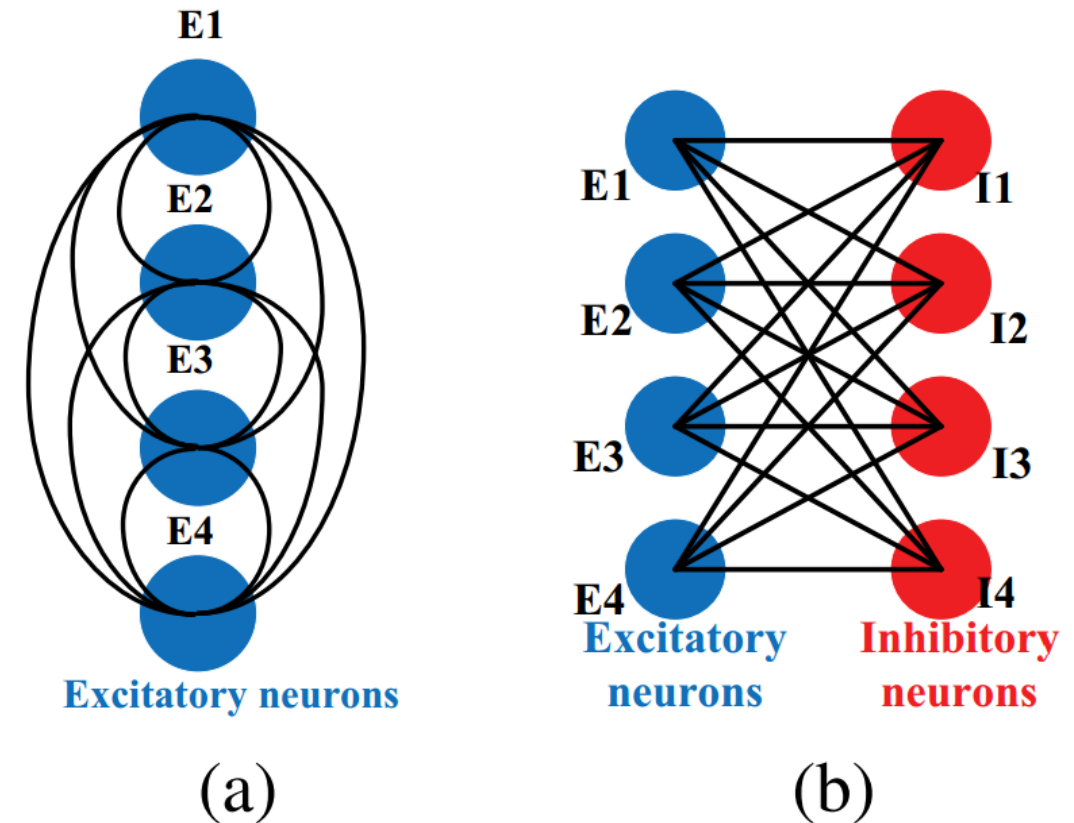


Fig. 5 The network topology of two lateral inhibition methods that are widely used in software simulations.

1. Introduction

1.3 Another two mechanisms demanded for STDP-based SNN

Homeostasis method:

Homeostasis method is used to reduce inhomogeneity, depressing the neuron with high firing frequency and potentiating the neuron with low firing frequency, to make sure that every neuron in the same layer has the same opportunity to fire and learn

1. Introduction

1.4 Memristor-based synapse

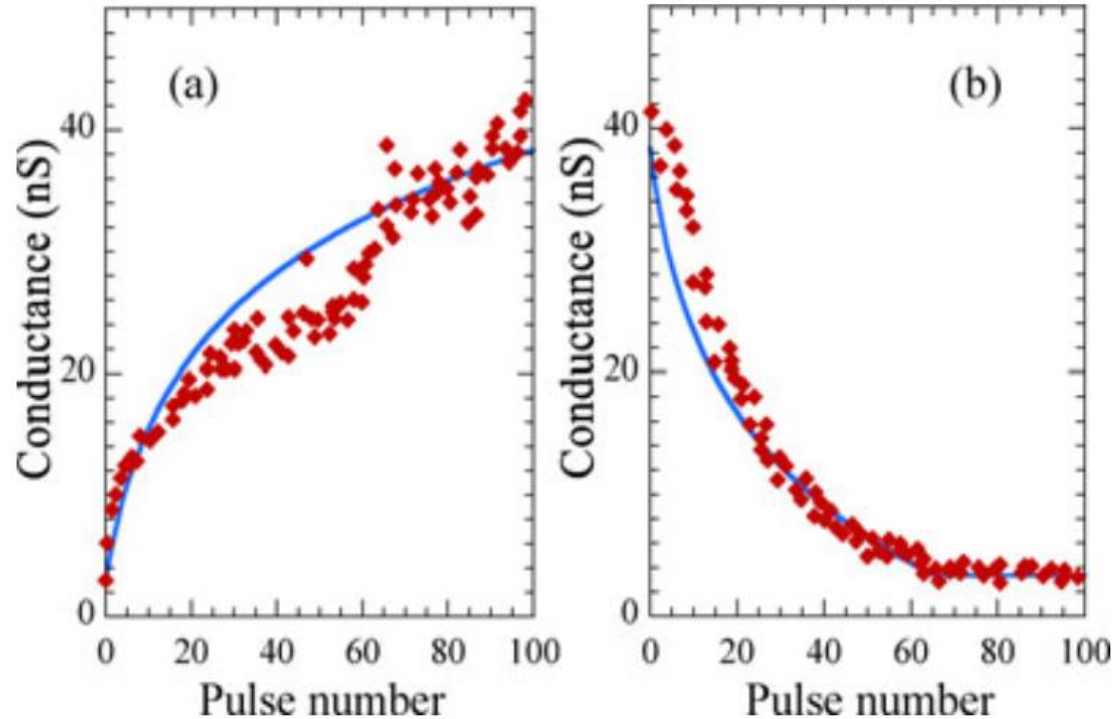


Fig. 6 The biological plausible STDP rules shown in experiments on memristor. The device conductance of memristor after positive voltage pulses (a) and after negative voltage pulses (b).

2. Methods

2.1 The proposed method to realize homeostasis and lateral inhibition for fully-connected and convolutional SNNs.

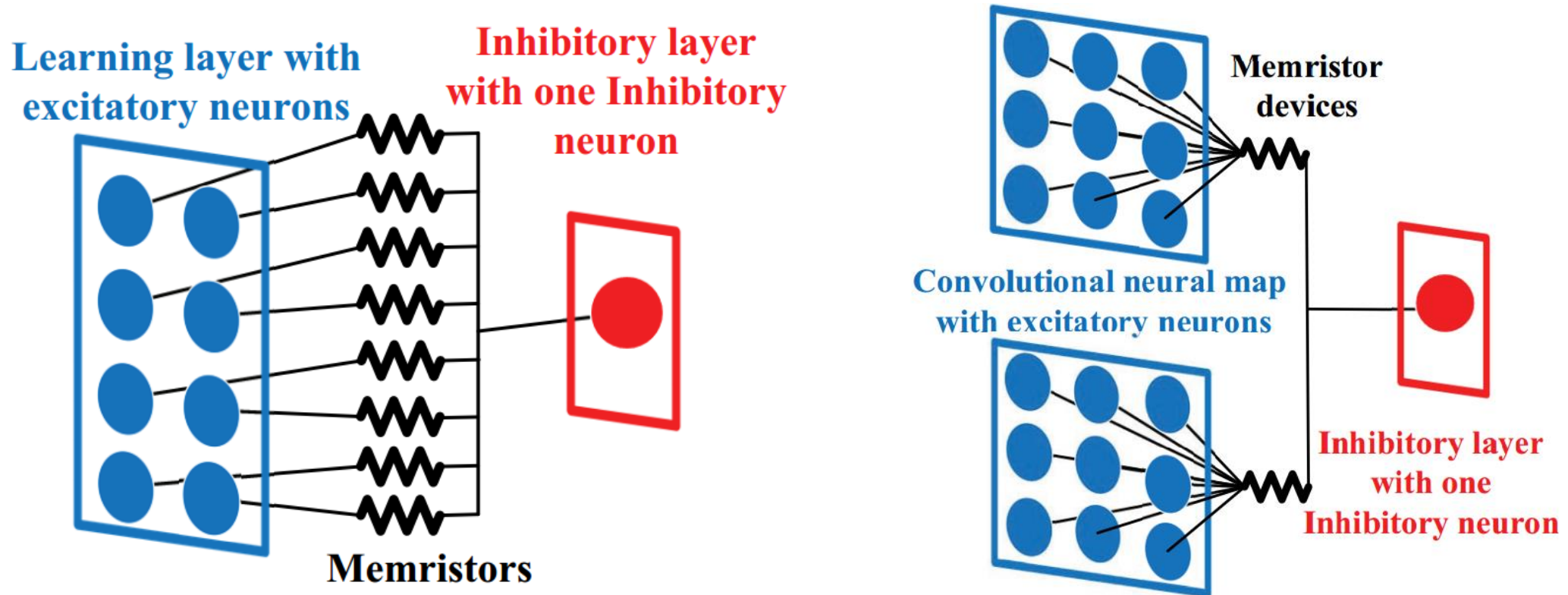


Fig. 8 The network schematics of fully-connected and convolutional SNNs using our proposed method to achieve lateral inhibition and homeostasis.

2. Methods

2.2 The program mechanism of the memristor in our methods

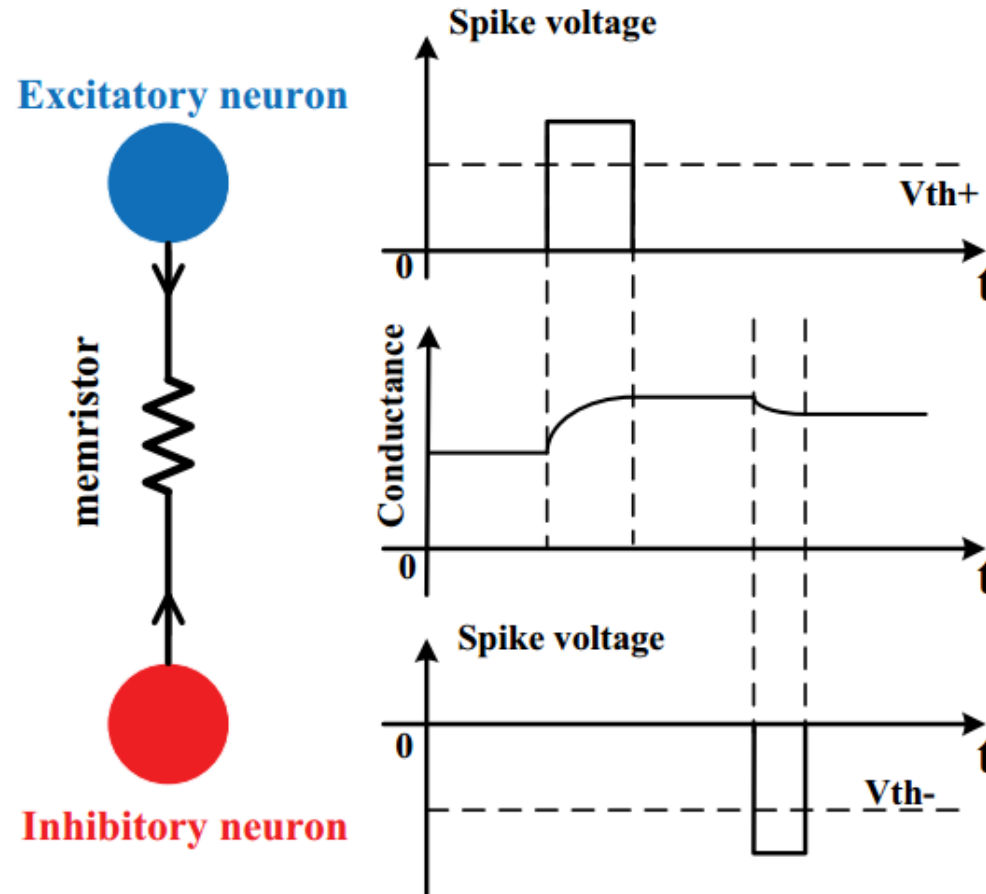


Fig. 9 Conductance variation of the memristor programmed by the transmitted spikes. The increase of conductance programmed by the spike from excitatory neuron is larger than that programmed by the spike from inhibitory neuron.

3. Simulation setup

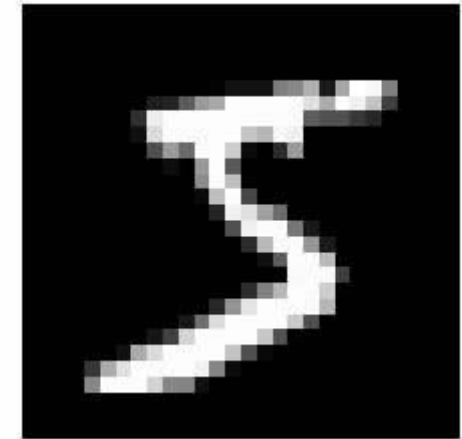
3.1 Software and dataset

Software simulations are performed on the open-source simulator of *Brian*.



The widely studied case of MNIST dataset is used as the benchmark task.

In this work, only the fully-connected SNN are simulated for the evaluation of our proposed method.



4. Simulation results

4.1 Test accuracy comparison

TABLE I
CLASSIFICATION ACCURACIES OF THE PROPOSED SNN WITH TWO
UNSUPERVISED SINGLE-LAYER SNNs ON MNIST TEST DATASET

Neuron number	Querlioz [12]	Diehl [13]	This work
100	85%	82.9%	87%
200	N/A	N/A	90.5%
300	93%	N/A	91.2%
400	N/A	87%	91.7%

4. Simulation results

4.2 Learning speed comparison

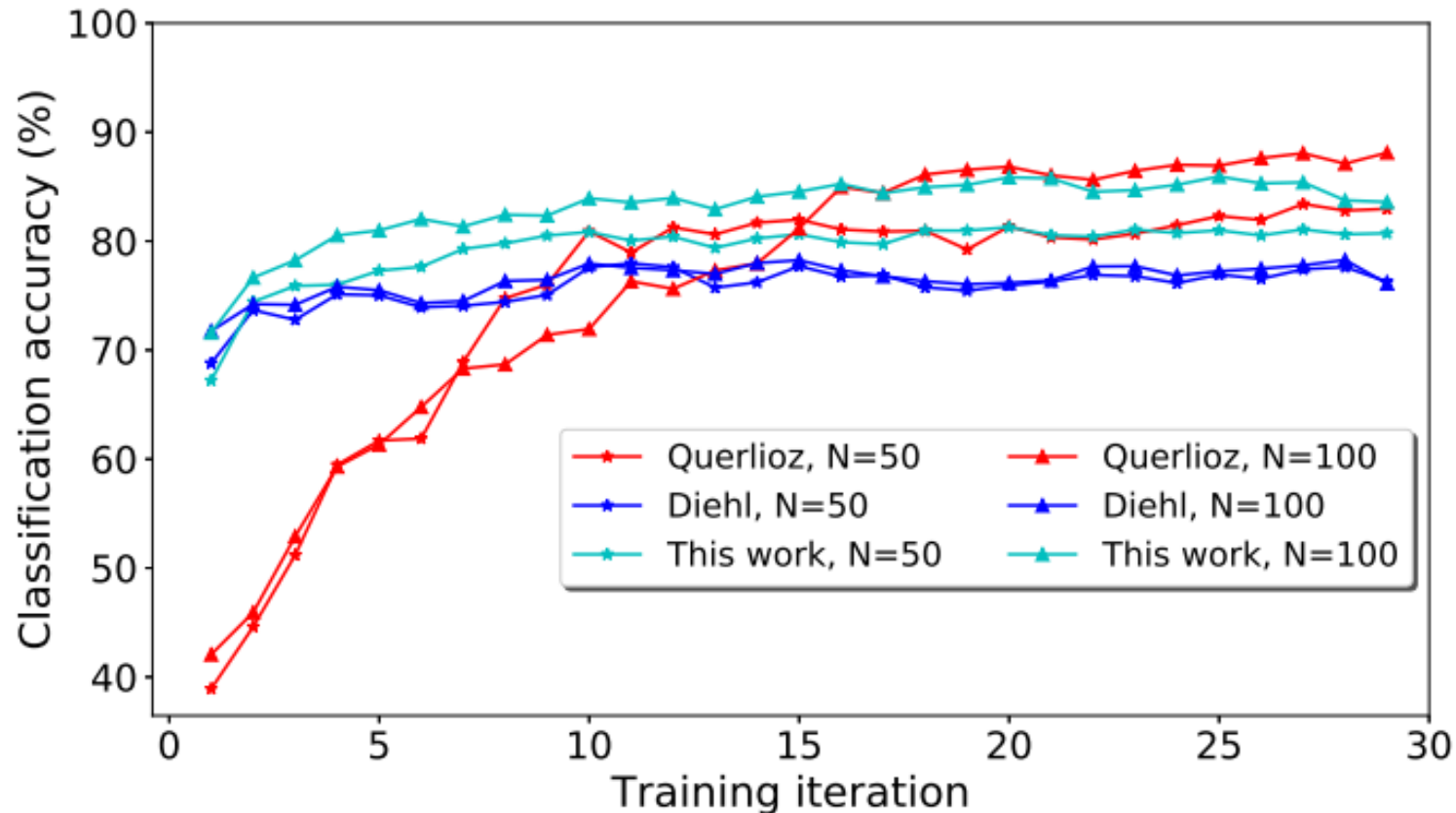


Fig. 10 The test accuracy of three SNNs with with different methods to achieve lateral inhibition and homeostasis after every 2000 training examples.

4. Simulation results

4.3 Spike number and spike number variation comparison

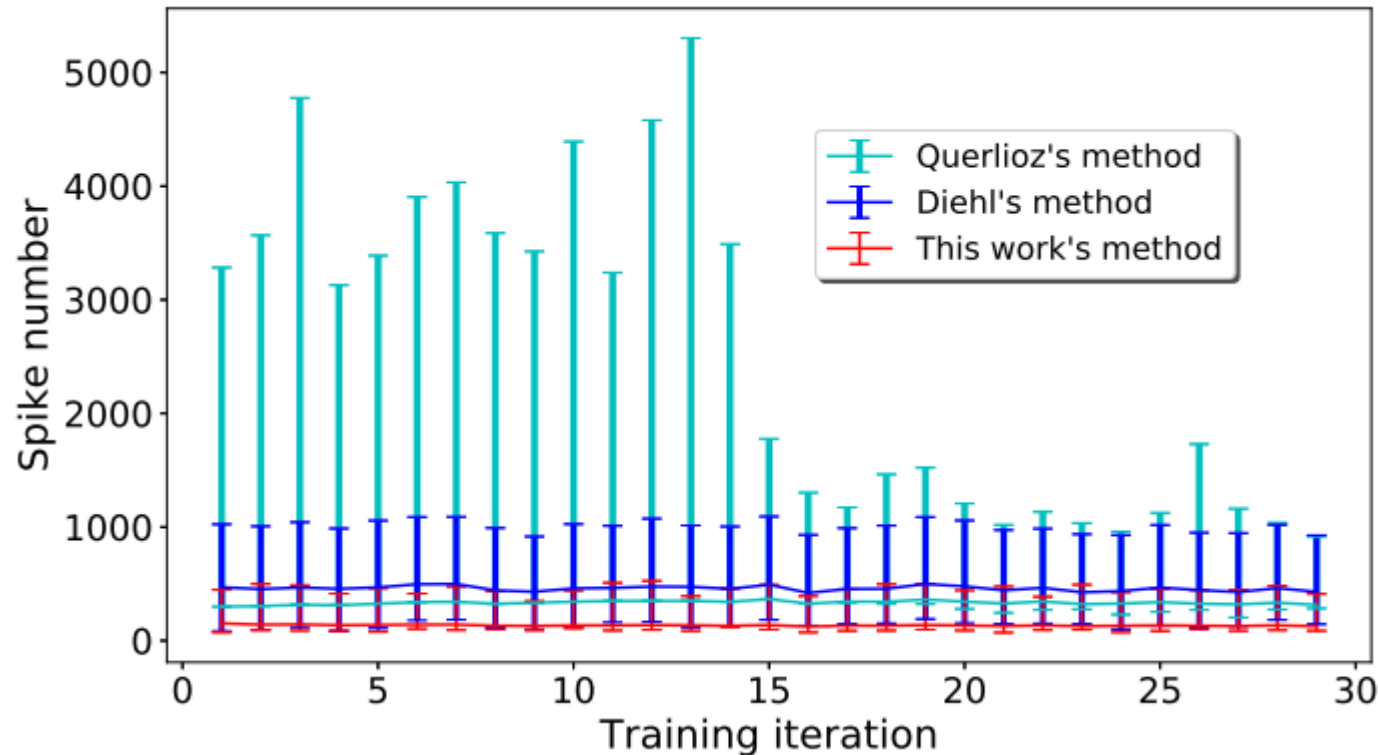


Fig. 11 Spike number and spike number variation of three learning algorithms with different methods to achieve lateral inhibition and homeostasis. The error bar indicates the spike number variation with maximum and minimum spike numbers of all the neurons during one training iteration of 2000 examples.

4. Simulation results

4.4.1 Robustness to non-ideal device characteristics

TABLE II
CLASSIFICATION ACCURACIES ON MNIST TEST DATASET WITH
DIFFERENT NUMBER OF RESISTIVE STATES

Neuron number	20 states	40 states	60 states	infinite states
50	76.9 %	80.0%	81.5%	83%
100	82.2%	84.9%	85.9%	87%

4. Simulation results

4.4.2 Robustness to non-ideal device characteristics

TABLE III
CLASSIFICATION ACCURACIES ON MNIST TEST DATASET WITH
DIFFERENT LEVEL VARIATIONS

Neuron number	15%	25%	35%	No variations
50	80.5 %	79.3%	78.3%	81.5%
100	84.9%	84.4%	83.5%	85.9%

4. Simulation results

4.4.3 Robustness to non-ideal device characteristics

TABLE IV
CLASSIFICATION ACCURACIES ON MNIST TEST DATASET WITH
DIFFERENT DEVICE OPEN PROBABILITY

Neuron number	5%	10%	15%	No open
50	76.76 %	75.9%	71.9%	79.3%
100	84.1%	80.2%	74.2%	84.4%

4. Simulation results

4.4.4 Robustness to non-ideal device characteristics

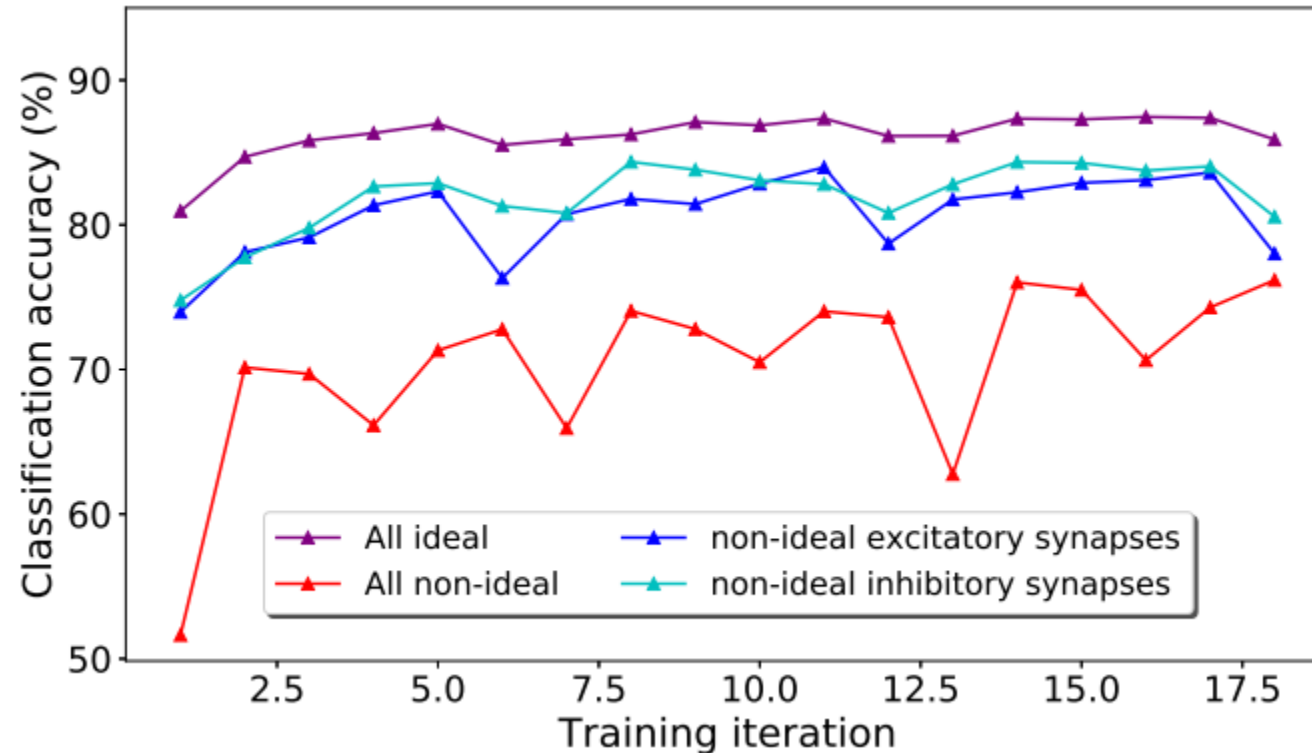


Fig 12. The test accuracy of our proposed SNN with 100 learning neurons after every training iteration of 10000 training examples. Non-ideal device characteristics are applied to all synapses, excitatory synapse, inhibitory synapses, and no synapses in four cases for comparison.

| 5. Conclusion

In this paper, we proposed a SNN using memristor-based inhibitory synapses to achieve lateral inhibition and homeostasis in a compact way.

- For the hardware implementation, our proposed SNN can improve the network scalability by reducing the connection number for lateral inhibition from N^2 to N and decrease the hardware complexity by leveraging the circuit of lateral inhibition to achieve homeostasis.
- Software simulations show that our proposed method can achieve higher learning efficiency ($2\times$) and comparable performance.
- Our approach demonstrates realistic application potential through evaluation considering the non-ideal characteristics of memristor devices.

End!

Thanks !

Q&A?